
Semiconductor devices - Mechanical and climatic test methods - Part 5: Steady-state temperature humidity bias life test (IEC 60749-5:2003)

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EUROPEAN STANDARD

EN 60749-5

NORME EUROPÉENNE

EUROPÄISCHE NORM

March 2003

ICS 31.080.01

English version

**Semiconductor devices -
Mechanical and climatic test methods
Part 5: Steady-state temperature humidity bias life test
(IEC 60749-5:2003)**

Dispositifs à semiconducteurs -
Méthodes d'essais mécaniques
et climatiques
Partie 5: Essai continu de durée
de vie sous température et humidité
avec polarisation
(CEI 60749-5:2003)

Halbleiterbauelemente -
Mechanische und klimatische Prüfverfahren
Teil 5: Lebensdauerprüfung bei
konstanter Temperatur und Feuchte
unter elektrischer Beanspruchung
(IEC 60749-5:2003)

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This European Standard was approved by CENELEC on 2003-03-01. CENELEC members are bound to comply with the CEN/CENELEC Internal Regulations which stipulate the conditions for giving this European Standard the status of a national standard without any alteration.

Up-to-date lists and bibliographical references concerning such national standards may be obtained on application to the Central Secretariat or to any CENELEC member.

This European Standard exists in three official versions (English, French, German). A version in any other language made by translation under the responsibility of a CENELEC member into its own language and notified to the Central Secretariat has the same status as the official versions.

CENELEC members are the national electrotechnical committees of Austria, Belgium, Czech Republic, Denmark, Finland, France, Germany, Greece, Hungary, Iceland, Ireland, Italy, Luxembourg, Malta, Netherlands, Norway, Portugal, Slovakia, Spain, Sweden, Switzerland and United Kingdom.

CENELEC

European Committee for Electrotechnical Standardization
Comité Européen de Normalisation Electrotechnique
Europäisches Komitee für Elektrotechnische Normung

Central Secretariat: rue de Stassart 35, B - 1050 Brussels

Foreword

The text of document 47/1661/FDIS, future edition 1 of IEC 60749-5, prepared by IEC TC 47, Semiconductor devices, was submitted to the IEC-CENELEC parallel vote and was approved by CENELEC as EN 60749-5 on 2003-03-01.

This mechanical and climatic test method, as it relates to steady-state temperature humidity bias life test, is a complete rewrite of the test contained in Clause 4B, Chapter 3 of EN 60749:1999.

The following dates were fixed:

- latest date by which the EN has to be implemented
at national level by publication of an identical
national standard or by endorsement (dop) 2003-12-01
- latest date by which the national standards conflicting
with the EN have to be withdrawn (dow) 2006-03-01

Annexes designated "normative" are part of the body of the standard.

In this standard, annex ZA is normative.

Annex ZA has been added by CENELEC.

Endorsement notice

The text of the International Standard IEC 60749-5:2003 was approved by CENELEC as a European Standard without any modification.

SIST EN 60749-5:2004

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Annex ZA (normative)

Normative references to international publications with their corresponding European publications

This European Standard incorporates by dated or undated reference, provisions from other publications. These normative references are cited at the appropriate places in the text and the publications are listed hereafter. For dated references, subsequent amendments to or revisions of any of these publications apply to this European Standard only when incorporated in it by amendment or revision. For undated references the latest edition of the publication referred to applies (including amendments).

NOTE When an international publication has been modified by common modifications, indicated by (mod), the relevant EN/HD applies.

<u>Publication</u>	<u>Year</u>	<u>Title</u>	<u>EN/HD</u>	<u>Year</u>
IEC 60749-4	- 1)	Semiconductor devices - Mechanical and climatic test methods Part 4: Damp heat, steady-state, highly accelerated stress test (HAST)	EN 60794-4	2002 2)

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1) Undated reference.

2) Valid edition at date of issue.

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**NORME
INTERNATIONALE
INTERNATIONAL
STANDARD**

**CEI
IEC**

60749-5

Première édition
First edition
2003-01

**Dispositifs à semiconducteurs –
Méthodes d'essais mécaniques et climatiques –**

**Partie 5:
Essai continu de durée de vie sous température
et humidité avec polarisation**

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**Semiconductor devices –
Mechanical and climatic test methods –**

**Part 5:
Steady-state temperature humidity
bias life test**

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International Electrotechnical Commission, 3, rue de Varembe, PO Box 131, CH-1211 Geneva 20, Switzerland
Telephone: +41 22 919 02 11 Telefax: +41 22 919 03 00 E-mail: inmail@iec.ch Web: www.iec.ch



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INTERNATIONAL ELECTROTECHNICAL COMMISSION

**SEMICONDUCTOR DEVICES –
MECHANICAL AND CLIMATIC TEST METHODS –**

Part 5: Steady-state temperature humidity bias life test

FOREWORD

- 1) The IEC (International Electrotechnical Commission) is a worldwide organization for standardization comprising all national electrotechnical committees (IEC National Committees). The object of the IEC is to promote international co-operation on all questions concerning standardization in the electrical and electronic fields. To this end and in addition to other activities, the IEC publishes International Standards. Their preparation is entrusted to technical committees; any IEC National Committee interested in the subject dealt with may participate in this preparatory work. International, governmental and non-governmental organizations liaising with the IEC also participate in this preparation. The IEC collaborates closely with the International Organization for Standardization (ISO) in accordance with conditions determined by agreement between the two organizations.
- 2) The formal decisions or agreements of the IEC on technical matters express, as nearly as possible, an international consensus of opinion on the relevant subjects since each technical committee has representation from all interested National Committees.
- 3) The documents produced have the form of recommendations for international use and are published in the form of standards, technical specifications, technical reports or guides and they are accepted by the National Committees in that sense.
- 4) In order to promote international unification, IEC National Committees undertake to apply IEC International Standards transparently to the maximum extent possible in their national and regional standards. Any divergence between the IEC Standard and the corresponding national or regional standard shall be clearly indicated in the latter.
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- 6) Attention is drawn to the possibility that some of the elements of this International Standard may be the subject of patent rights. The IEC shall not be held responsible for identifying any or all such patent rights.

International Standard IEC 60749-5 has been prepared by IEC technical committee 47: Semiconductor devices.

The text of this standard is based on the following documents:

FDIS	Report on voting
47/1661/FDIS	47/1678/RVD

Full information on the voting for the approval of this standard can be found in the report on voting indicated in the above table.

This publication has been drafted in accordance with the ISO/IEC Directives, Part 2.

This mechanical and climatic test method, as it relates to steady-state temperature humidity bias life test, is a complete re-write of the test contained in Clause 4B, Chapter 3 of IEC 60749.

The committee has decided that the contents of this publication will remain unchanged until 2007. At this date, the publication will be

- reconfirmed;
- withdrawn;
- replaced by a revised edition, or
- amended.

SEMICONDUCTOR DEVICES – MECHANICAL AND CLIMATIC TEST METHODS –

Part 5: Steady-state temperature humidity bias life test

1 Scope

This part of IEC 60749 provides a steady-state temperature and humidity bias life test for the purpose of evaluating the reliability of non-hermetic packaged solid-state devices in humid environments.

NOTE This test is in general accord with IEC 60068-2-3 (withdrawn)¹, but due to specific requirements of semiconductors, the following text is applied.

This test method is considered destructive.

2 Normative references

The following referenced documents are indispensable for the application of this document. For dated references, only the edition cited applies. For undated references, the latest edition of the referenced document (including any amendments) applies.

IEC 60749-4, *Semiconductor devices – Mechanical and climatic test methods – Part 4: Damp heat, steady-state, highly accelerated stress test (HAST)*

<https://standards.iteh.ai/catalog/standards/sist/aa4c35b3-58a0-4dcc-acad-2bfe53ec9a61/sist-en-60749-5-2004>

3 General

This test employs conditions of temperature, humidity and bias which accelerate the penetration of moisture through the external protective material (encapsulant or seal) or along the interface between the external protective material and the metallic conductors which pass through it.

Where both this steady-state, humidity bias test and the damp heat, highly accelerated stress test (HAST) of IEC 60749-4 are performed, the results of this 85 °C/85 % RH steady-state test will take priority over the results of the HAST test, which is an accelerated test designed to activate the same failure mechanisms.

¹ IEC 60068-2-3, *Environmental testing – Part 2: Tests – Test Ca: Damp heat steady state.*